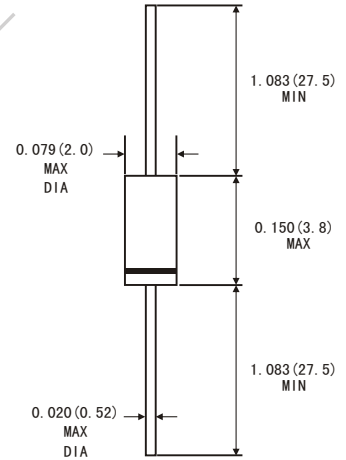


### FEATURES

- Metal-on-silicon junction
  - Low turn-on voltage
  - Ultrafast switching speed
  - Primarily intended for high level UHF mixers and ultrafast switching applications
- The diode is also available in the MiniMELF case with type designation LL29.
- High temperature soldering guaranteed: 260°C / 10 seconds at terminals
  - Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### DO-35



### MECHANICAL DATA

- Case: DO-35 glass case
- Polarity: color band denotes cathode end
- Weight: Approx. 0.13 gram

### ABSOLUTE RATINGS(LIMITING VALUES)

	Symbols	Value	Units
Peak Reverse Voltage	V <sub>RRM</sub>	5	V
Forward Continuous Current	I <sub>F</sub>	30	mA
Surge non repetitive forward current t <sub>p</sub> ≤ 1s	I <sub>FSM</sub>	60	mA
Junction and Storage temperature range	T <sub>STG</sub>	-65 to +150	°C
	T <sub>J</sub>	-65 to +150	°C
Maximum Lead Temperature for Soldering during 10s at 4mm from Case	T <sub>L</sub>	230	°C

### ELECTRICAL CHARACTERISTICS

	Symbols	Min.	Typ.	Max.	Units
Reverse breakover voltage at I <sub>R</sub> =100μA	V <sub>R</sub>	5			V
Leakage current at V <sub>R</sub> =1V	I <sub>R</sub>			50	nA
Forward voltage drop at I <sub>F</sub> =10mA Test pulse: t <sub>p</sub> ≤ 300μs δ < 2%	V <sub>F</sub>			0.55	V
Junction Capacitance at V <sub>R</sub> =0V, f=1GHz	C <sub>J</sub>			1.0	pF
Thermal resistance	R <sub>θJA</sub>			400	K/W

# RATINGS AND CHARACTERISTIC CURVES BAT29

Figure 1. forward current versus forward voltage (typical values)

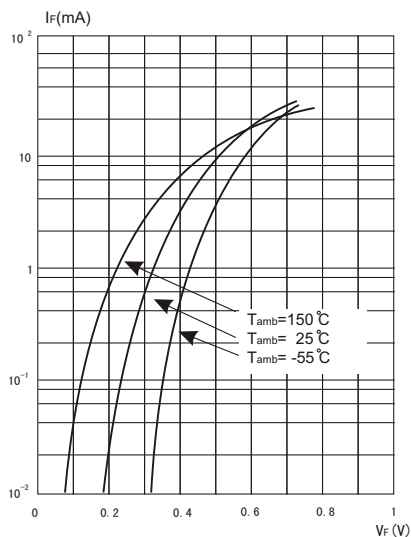


Figure 2. Capacitance  $C_j$  versus reverse applied voltage  $V_R$  (typical values)

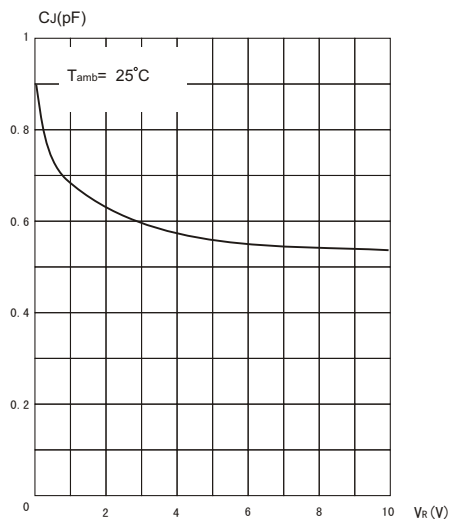


Figure 3. Reverse current versus ambient temperature

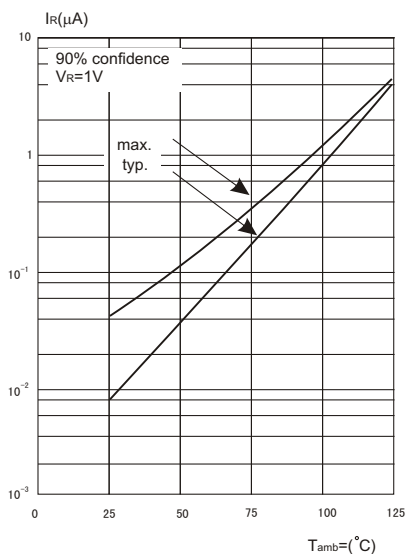


Figure 4. Reverse current versus continuous Reverse voltage (typical values)

